

# Test Strategy for Mass Transfer Photodiodes

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# Albis Optoelectronics – Detecting Solutions

- Designer, developer and manufacturer of high-speed III-V photodiodes (up to 70 GHz) and avalanche photodiodes (up to 25 GHz) based on InP and GaAs.
- 20 years of excellence in III-V photodiode manufacturing with over 40 million photodiodes sold to date.
- Qualified technology and products with long track record of reliability.
- Own clean room production facilities
  - In-house front-end to back-end III-V wafer processing and testing.
  - Flip-chip mounting and packaging infrastructure.
- Design and fabrication chips, chip-on-carrier and packaged photodiodes.







#### **Overview – Mass Transfer PD**



- Mass transfer photodiode concept
- Yield challenge
- Testing strategy
- Conclusion



The Albis InP mass transfer PD (MTPD) is a releasable photodiode designed for efficient substrate removal and transfer via pick-and-place on target substrates.

### Mass Transfer PD (MTPD) concept



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# Mass Transfer PD (MTPD) concept



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### **PD on Waveguide**





- MTPD
  - Enables evanescent / grating coupler.
  - Heterogenous integration of PD on PIC platform (SiN, Glass, Polymer, TFNL).
  - Cost efficient electrical interconnects on wafer level (no wire bond or soldering).
  - Small chip size enables high density integration (many components).



#### **PD on TIA**





- MTPD
  - Enables heterogenous integration of PD on highspeed TIA wafers.
  - Parallel electrical interconnect deposition on full TIA wafer.
  - Low parasitic interconnects / cross-talk.
  - Testability on wafer level.

### **Yield Challenge**



Process  
source waferReleasePick-and-placeProcess on  
target wafer
$$Y_{swp} = 99 \%$$
 $Y_{mtr} = 99 \%$  $Y_{twp} = 99 \%$ 



$$Y(n) = (Y_{swp})^{n} * (Y_{mtr})^{n} * (Y_{twp})^{n}$$

#### **Mass Transfer Yield**



• Mass transfer of **untested** components.



• Low yield of individual steps results in costly failure of full assembly.

#### **Mass Transfer Yield**



• Mass transfer of tested and known-good-chiplet (KGC).



• Testing components before assembly improves yield.

### **Test Strategy – Die Validation**



 Multi-project wafer (MPW) with standardize testing procedure for die and wafer validation.



#### **Test strategy for MTPD**









	No probe pad	Probe pad	Sacrificial probe pad
Material consumption	small	large	small
Integration density	high	medium	high
Testability	die validation	100%	100%
Assembly yield	low	high	medium
Cost	lowest	low	medium

• Testing strategy is part of the heterogenous product design.

#### **Summary**



#### Innovative Photodiode Form Factor:

- The Albis mass transfer PD (MTPD) is a releasable photodiode designed for efficient substrate removal and transfer via pick-andplace on target substrates.
- It enables new heterogenous, high-density integration and new illumination schemes.
- Quality and Performance Focus:
  - Tested MTPD technology with high quality, yield, and performance.

#### Active R&D and Prototyping:

- Engages in R&D projects and customer-driven prototypes.
- Promotes MPW runs to showcase the compatibility and feasibility of Albis PD technology with mass transfer approaches and target substrates.



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